Triacs

Silicon Bidirectional Thyristors

Designed primarily for full-wave ac control applications, such as solid-state relays, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied anode voltage with positive or negative gate triggering.

- Blocking Voltage to 600 Volts
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Gate Triggering Guaranteed in Four Modes
- **%** Indicates UL Registered File #E69369
- Device Marking: Logo, Device Type, e.g., MAC320A8FP, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to +125°C, Sine Wave 50 to 60 Hz, Gate Open)	VDRM, VRRM	600	Volts
On-State RMS Current (T _C = +75°C, Full Cycle Sine Wave 50 to 60 Hz)(2)	IT(RMS)	20	Amps
Peak Non–Repetitive Surge Current (One Full Cycle, 60 Hz, T _C = +75°C, preceded and followed by rated current)	ITSM	150	Amps
Peak Gate Power (T _C = +75°C, Pulse Width = 2 μs)	PGM	20	Watts
Peak Gate Voltage (T _C = +75°C, Pulse Width = 2 μs)	VGМ	10	Volts
Average Gate Power (T _C = +75°C, t = 8.3 ms)	PG(AV)	0.5	Watt
Peak Gate Current (T _C = +75°C, Pulse Width = 2 μs)	IGM	2.0	Amps
RMS Isolation Voltage (T _A = 25°C, Relative Humidity ≤ 20%) (%)	V _(ISO)	1500	Volts
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

⁽¹⁾ VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



ON Semiconductor

http://onsemi.com

ISOLATED TRIACs (%) 20 AMPERES RMS 600 VOLTS





ISOLATED TO-220 Full Pack CASE 221C STYLE 3

PIN ASSIGNMENT			
1 Main Terminal 1			
2	Main Terminal 2		
3	Gate		

ORDERING INFORMATION

Device	Package	Shipping	
MAC320A8FP	ISOLATED TO220FP	500/Box	

⁽²⁾ The case temperature reference point for all TC measurements is a point on the center lead of the package as close as possible to the plastic body.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1.8	°C/W
Thermal Resistance, Case to Sink	$R_{\theta}CS$	2.2	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Second	onas I I L		260		°C
ELECTRICAL CHARACTERISTICS (T _C = 25°C unless otherwise noted; E	Electricals apply in	both direc	ctions)		
Characteristic	Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current $(V_D = Rated \ V_{DRM}, \ V_{RRM}; Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = +125^{\circ}C$	I _{DRM} , I _{RRM}	_	=	10 2.0	μA mA
OFF CHARACTERISTICS	•	•	-		
Peak On-State Voltage (I _{TM} = ±28 A Peak; Pulse Width = 1 to 2 ms, Duty Cycle ≤ 2%)	VTM	_	1.4	1.7	Volts
ON CHARACTERISTICS	•				
Peak Gate Trigger Current (Main Terminal Voltage = 12 Vdc, R _L = 100 Ohms) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-) MT2(-), G(-)	^I GT	 - - - -	_ _ _ _	50 50 50 75	mA
Peak Gate Trigger Voltage (Main Terminal Voltage = 12 Vdc, R _L = 100 Ohms) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-) MT2(-), G(+)	VGT	_ _ _ _	0.9 0.9 1.1 1.4	2.0 2.0 2.0 2.5	Volts
Gate Non–Trigger Voltage (Main Terminal Voltage = 12 V, R _L = 100 Ω , T _J = +110°C) All Four Quadrants	V _{GD}	0.2	_	_	Volts
Holding Current (Main Terminal Voltage = 12 Vdc, Gate Open, Initiating Current = ±200 mA)	lн	_	6.0	40	mA
	-	•	-	-	

DYNAMIC CHARACTERISTICS

 $(V_D = Rated \ V_{DRM}, \ I_{TM} = 28 \ A, \ I_{GT} = 120 \ mA,$ Rise Time = 0.1 μs , Pulse Width = 2 μs)

Turn-On Time

Critical Rate of Rise of Commutation Voltage	dv/dt(c)	_	5.0	_	V/μs
(V _D = Rated V _{DRM} , I _{TM} = 28 A, Commutating di/dt = 10 A/ms,					
Gate Unenergized, $T_C = +75^{\circ}C$)					

tgt

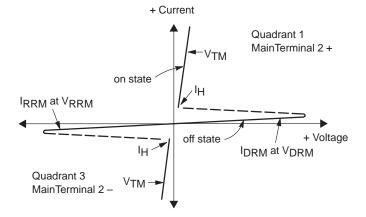
μs

1.5

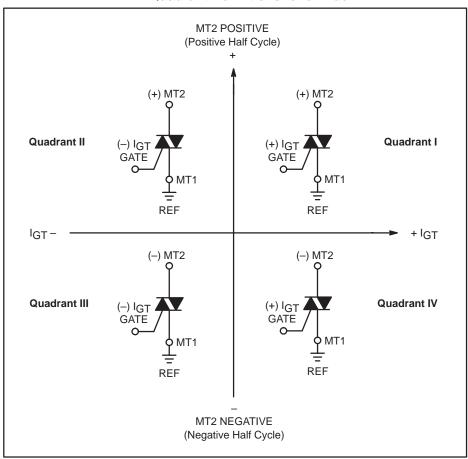
10

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
lΗ	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

TYPICAL CHARACTERISTICS

100

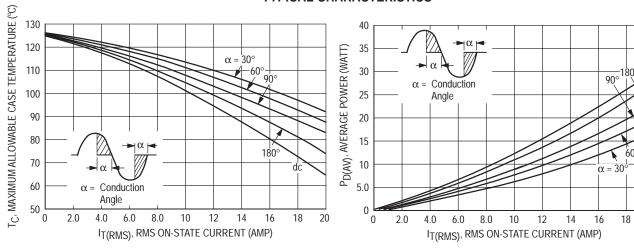


Figure 1. RMS Current Derating

Figure 2. On-State Power Dissipation

20

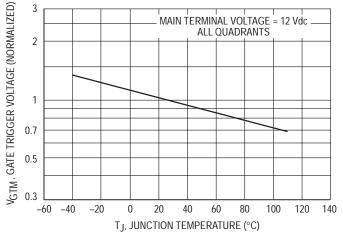


Figure 3. Typical Gate Trigger Voltage

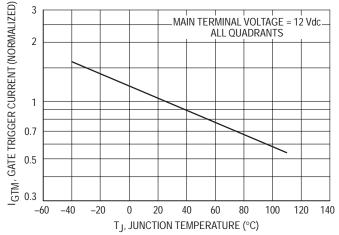


Figure 4. Typical Gate Trigger Current

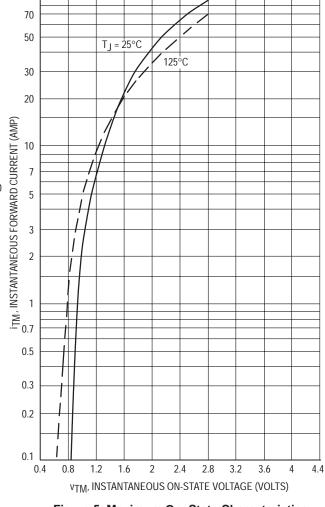


Figure 5. Maximum On-State Characteristics

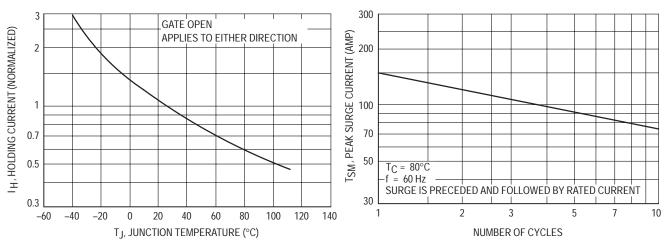


Figure 6. Typical Holding Current

Figure 7. Maximum Nonrepetitive Surge Current

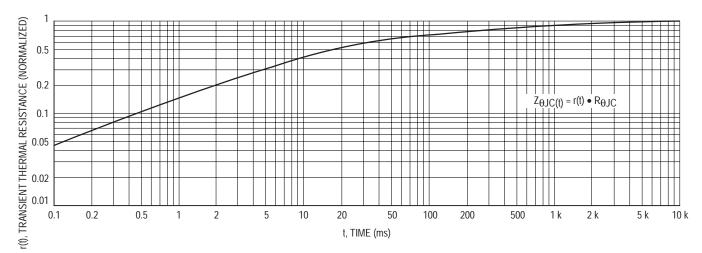
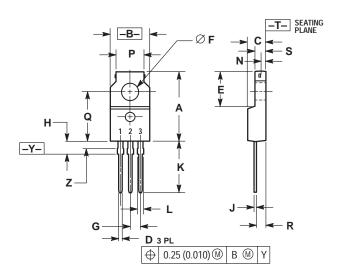


Figure 8. Thermal Response

PACKAGE DIMENSIONS

ISOLATED TO-220 Full Pack

CASE 221C-02 ISSUE C



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.680	0.700	17.28	17.78
В	0.388	0.408	9.86	10.36
С	0.175	0.195	4.45	4.95
D	0.025	0.040	0.64	1.01
Ε	0.340	0.355	8.64	9.01
F	0.140	0.150	3.56	3.81
G	0.100 BSC		2.54 BSC	
Н	0.110	0.155	2.80	3.93
J	0.018	0.028	0.46	0.71
K	0.500	0.550	12.70	13.97
L	0.045	0.070	1.15	1.77
N	0.049		1.25	
Р	0.270	0.290	6.86	7.36
Q	0.480	0.500	12.20	12.70
R	0.090	0.120	2.29	3.04
S	0.105	0.115	2.67	2.92
Z	0.070	0.090	1.78	2.28

STYLE 3: PIN 1. MT 1

MT 2
 GATE

Notes

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